NSN 5961-01-197-9725

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-197-9725 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches Overall Diameter: Between 0.335 inches and 0.370 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 700.0 collector to base voltage, dc and 700.0 collector to emitter reverse voltage and 5.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** Between 250.00 milliamperes source cutoff current and 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 08748-tr24 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No